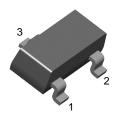
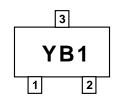


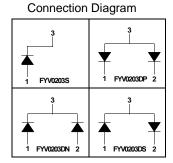
FYV0203S/DN/DP/DS



SOT-23



MarkingFYV0203S = YB1 FYV0203DP = YB3
FYV0203DN = YB2 FYV0203DS = YB4



Schottky Diode

Absolute Maximum Ratings TA=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{RRM}	Maximum Repetitive Reverse Voltage	30	V
I _{F(AV)}	Average Rectified Forward Current	0.2	Α
I _{FSM}	Non-repetitive Peak Surge Current Pulse Width = 1.0s	0.6	А
T _{STG}	Storage Temperature Range	-65 to +150	°C
T _J	Operating Junction Temperature	150	°C

Thermal Characteristics

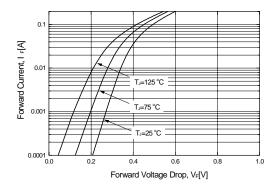
Symbol	Parameter	Value	Units
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	430	°C/W

Electrical Characteristics TA=25°C unless otherwise noted

Symbol	Parameter		Min.	Тур.	Max.	Units
V _F *	Forward Voltage Drop					mV
•	I _F = 0.1mA		-	210	240	
	$I_{F} = 1 \text{mA}$		-	270	320	
	I _F = 10mA		-	340	400	
	I _F = 30mA		-	390	500	
	i _F = 100mA I _F = 200mA		-	485	800	
			-	600	1000	
I _R *	Reverse Current					uA
	@ Rated V _R	T _A = 25 °C	-	0.2	2	
		T _A = 25 °C T _A = 125 °C	-	130	-	
C _T	Total Capacitance	•				pF
	$V_{R} = 1V$, f = 1.0 MHz		-	-	10	
rr	Reverse Recovery Time				İ	ns
**	$I_{\rm F} = I_{\rm R} = 10$ mA, $I_{\rm RR} = 1$ mA, $I_{\rm L} = 100$ Ω		-	-	5	

^{*} Pulse Test: Pulse Width=300µs, Duty Cycle=2%

Typical Characteristics



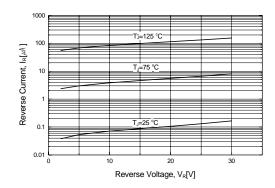


Figure 1. Typical Forward Voltage Characteristics

Figure 2. Typical Reverse Current vs. Reverse Voltage

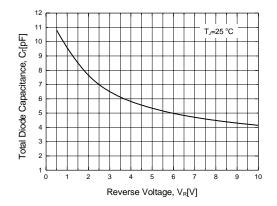
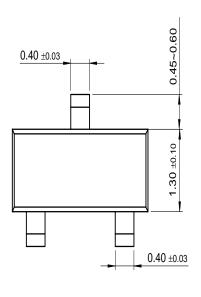


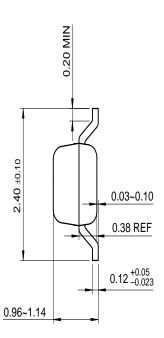
Figure 3. Total Diode Capacitance

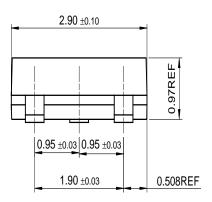
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Package Dimensions

SOT-23







Dimensions in Millimeters

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